

HD74HC112

Dual J-K Flip-Flops (with Preset and Clear)

REJ03D0562-0200
 (Previous ADE-205-435)
 Rev.2.00
 Oct 11, 2005

Description

Each flip-flop has independent J, K, preset, clear and clock inputs and Q and \bar{Q} outputs. This device is edge sensitive to the clock input and change state on the negative going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input.






Features

- High Speed Operation: t_{pd} (Clock to Q) = 17 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 2 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC112P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	—
HD74HC112FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs			Outputs			
Preset	Clear	Clock	J	K	Q	\bar{Q}
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H^*	H^*
H	H		L	L	No change	
H	H		L	H	L	H
H	H		H	L	H	L
H	H		H	H	Toggle	
H	H	L	X	X	No change	
H	H	H	X	X	No change	
H	H		X	X	No change	

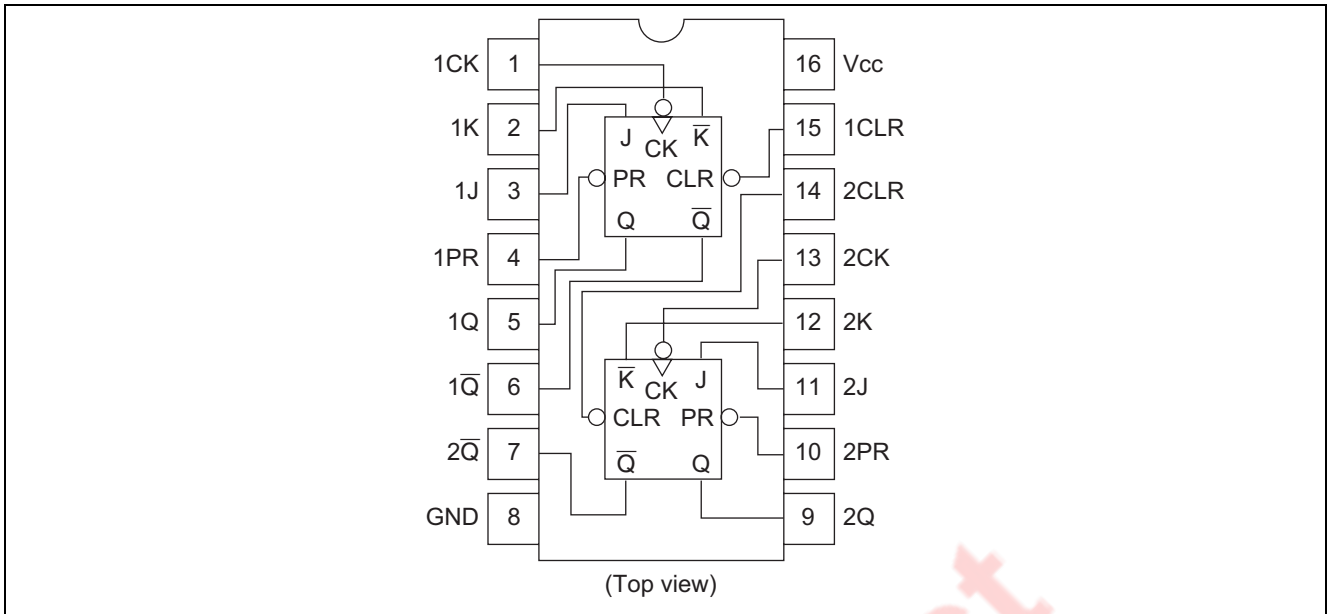
H : High level

L : Low level

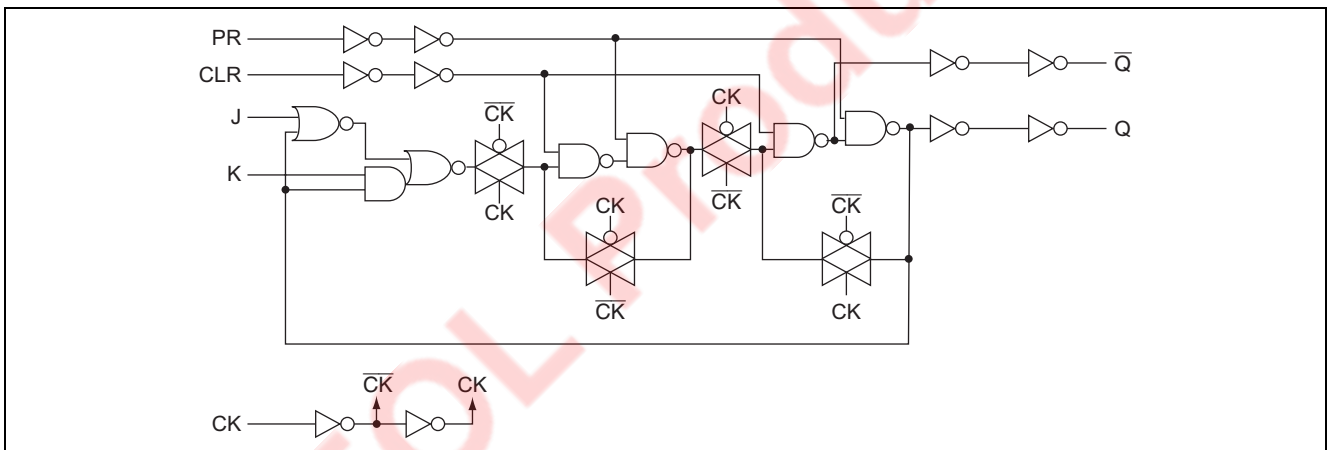
X : Irrelevant

Note: 1. Q and \bar{Q} will remain High as long as Preset and Clear are Low, but Q and \bar{Q} are unpredictable, if Preset and Clear go High simultaneously.

Pin Arrangement



Logic Diagram (1/2)



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	V _{in} , V _{out}	-0.5 to V _{CC} +0.5	V
Input / Output diode current	I _{IK} , I _{OK}	±20	mA
Output current	I _O	±25	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±50	mA
Power dissipation	P _T	500	mW
Storage temperature	T _{stg}	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	T_a	-40 to 85	°C	
Input rise / fall time ^{*1}	t_r, t_f	0 to 1000	ns	$V_{CC} = 2.0\text{ V}$
		0 to 500		$V_{CC} = 4.5\text{ V}$
		0 to 400		$V_{CC} = 6.0\text{ V}$

Note: 1. This item guarantees maximum limit when one input switches.
 Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{ to }+85^\circ\text{C}$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}\text{ or }V_{IL}$	$I_{OH} = -20\ \mu\text{A}$
		4.5	4.4	4.5	—	4.4	—			$I_{OH} = -4\ \text{mA}$
		6.0	5.9	6.0	—	5.9	—			$I_{OH} = -5.2\ \text{mA}$
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
		6.0	—	—	—	—	—			
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}\text{ or }V_{IL}$	$I_{OL} = 20\ \mu\text{A}$
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			$I_{OL} = 4\ \text{mA}$
6.0	—	—	0.26	—	0.33	$I_{OL} = 5.2\ \text{mA}$				
Input current	I_{in}	6.0	—	—	± 0.1	—	± 1.0	μA	$V_{in} = V_{CC}\text{ or GND}$	
Quiescent supply current	I_{CC}	6.0	—	—	2.0	—	20	μA	$V_{in} = V_{CC}\text{ or GND}, I_{out} = 0\ \mu\text{A}$	

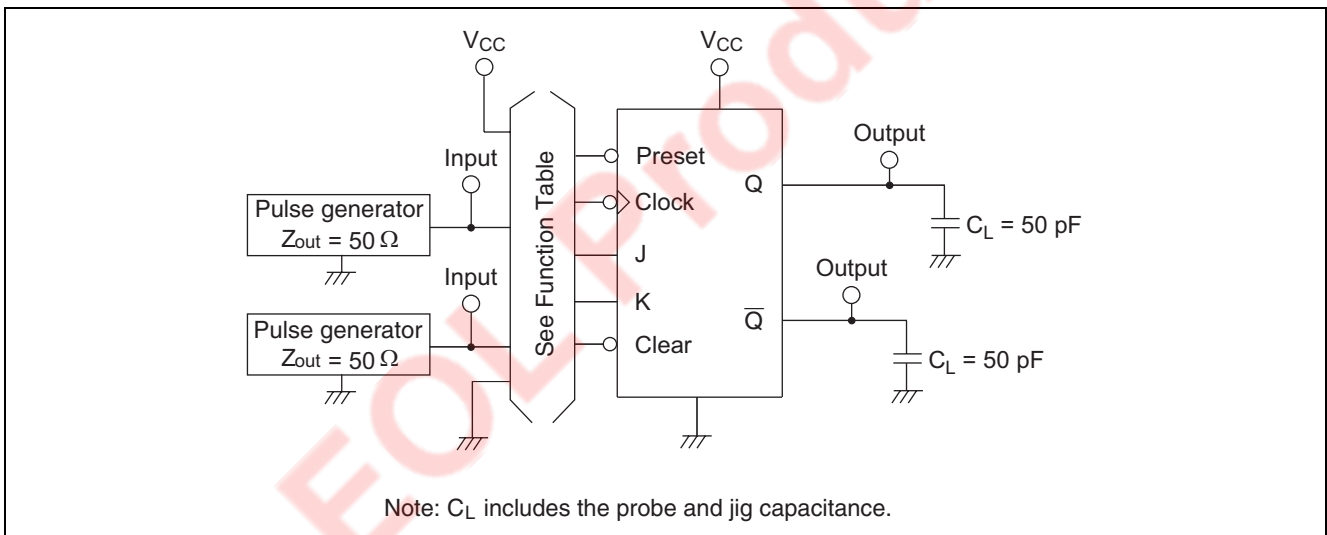
Switching Characteristics ($C_L = 50\ \text{pF}$, Input $t_r = t_f = 6\ \text{ns}$)

Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40\text{ to }+85^\circ\text{C}$		Unit	Test Conditions						
			Min	Typ	Max	Min	Max								
Maximum clock frequency	f_{max}	2.0	—	—	6	—	5	MHz							
		4.5	—	—	30	—	24								
		6.0	—	—	35	—	28								
Propagation delay time	t_{PLH}, t_{PHL}	2.0	—	—	150	—	190	ns	Clock to Q or \bar{Q}						
		4.5	—	17	30	—	38								
		6.0	—	—	26	—	33								
		2.0	—	—	140	—	175					ns	Clear to Q or \bar{Q}		
		4.5	—	15	28	—	35								
		6.0	—	—	24	—	30								
	t_{PLH}, t_{PHL}	2.0	—	—	140	—	175	ns	Preset to Q or \bar{Q}						
		4.5	—	16	28	—	35								
		6.0	—	—	24	—	30								

Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

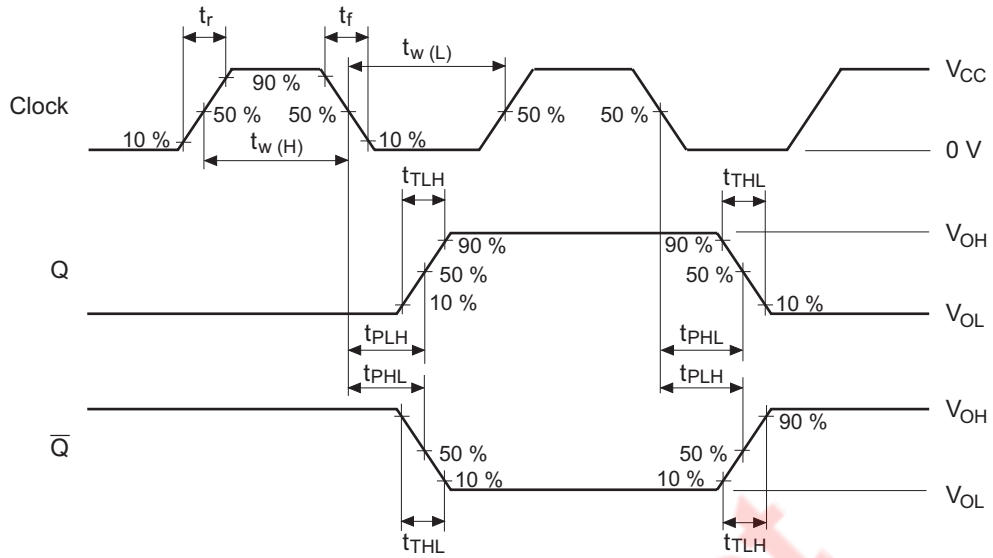
Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } +85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Pulse width	t_w	2.0	80	—	—	100	—	ns	Clear, Clock
		4.5	16	9	—	20	—		
		6.0	14	—	—	17	—		
Setup time	t_{su}	2.0	100	—	—	125	—	ns	J or K to Clock
		4.5	20	3	—	25	—		
		6.0	17	—	—	21	—		
Hold time	t_h	2.0	5	—	—	5	—	ns	Clock to J or K
		4.5	5	-2	—	5	—		
		6.0	5	—	—	5	—		
Removal time	t_{rem}	2.0	100	—	—	125	—	ns	Clear to Clock
		4.5	20	2	—	25	—		
		6.0	17	—	—	21	—		
Output rise/fall time	t_{TLH}, t_{THL}	2.0	—	—	75	—	95	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	C_{in}	—	—	5	10	—	10	pF	

Test Circuit

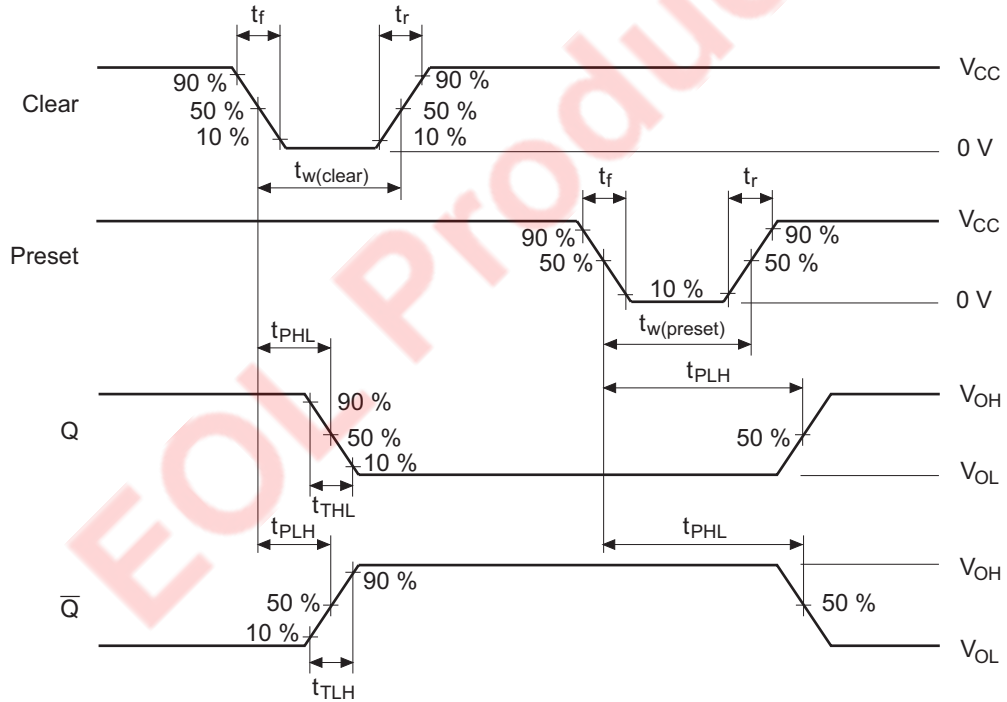


Waveforms

• Waveform – 1

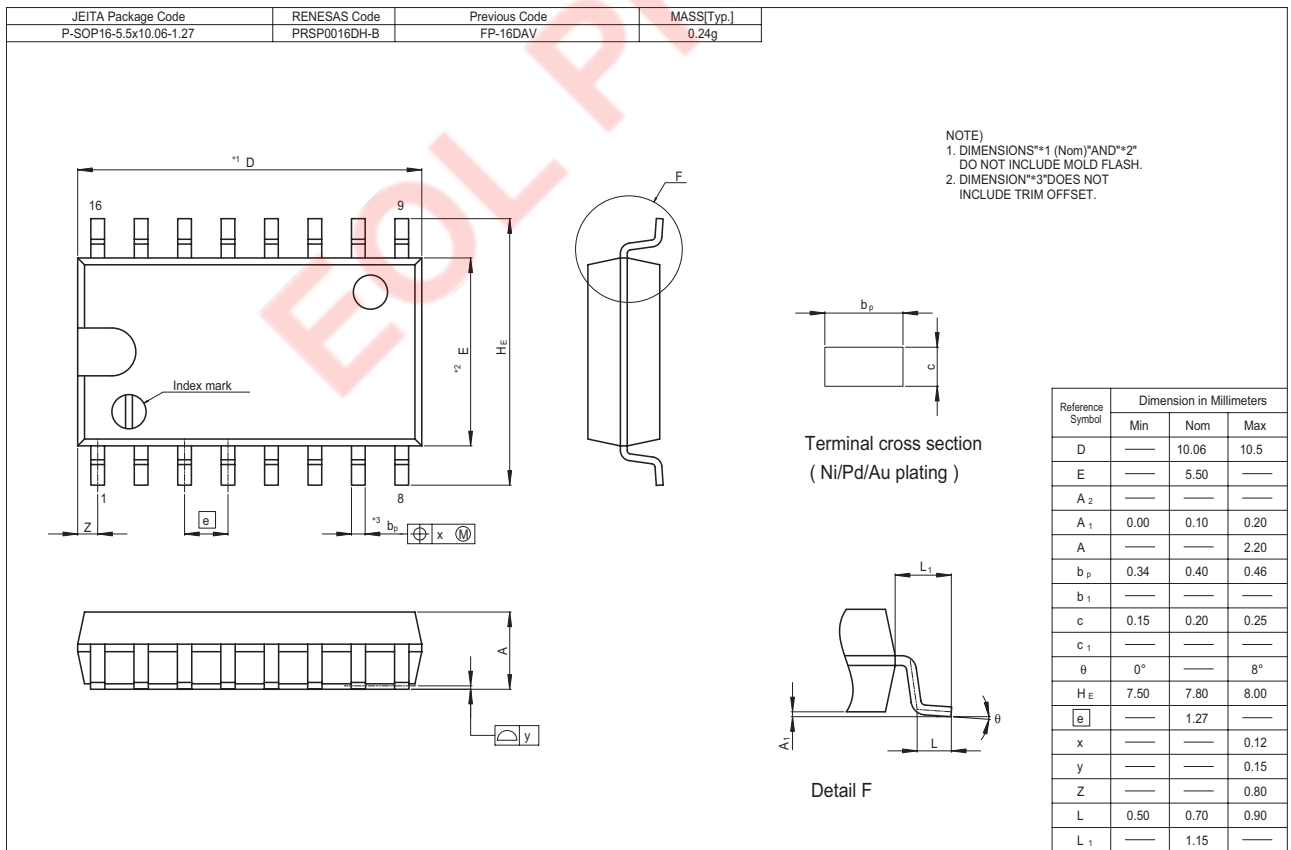
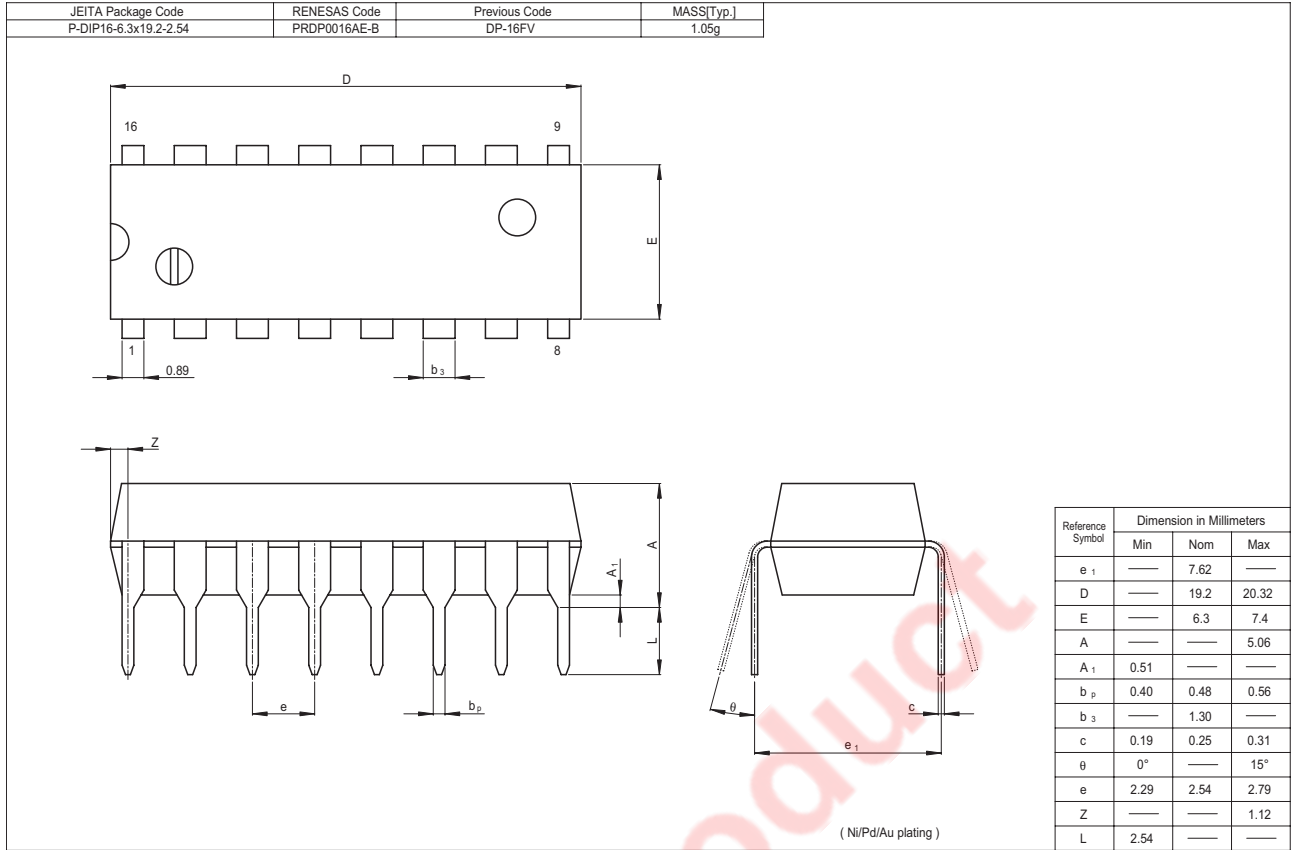


• Waveform – 2



- Notes: 1. Input waveform: $PRR \leq 1 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$
 2. The output are measured one at a time with one transition per measurement.

Package Dimensions



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